

Thermal Resistance

Symbol	Parameter	Тур.	Max.	Units
R _{eJC}	Junction-to-Case 90		0.65	°C/W
R _{0JA}	Junction-to-Ambient (PCB Mount) ®		40	

Static @ T_J = 25°C (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Units	Conditions
V _{(BR)DSS}	Drain-to-Source Breakdown Voltage	40			V	$V_{GS} = 0V, I_{D} = 250 \mu A$
$\Delta V_{(BR)DSS} / \Delta T_J$	Breakdown Voltage Temp. Coefficient		0.035		V/°C	Reference to 25°C, $I_D = 1.0 \text{mA}^{\odot}$
R _{DS(on)}	Static Drain-to-Source On-Resistance		1.0	1.3	mΩ	V _{GS} = 10V, I _D = 100A ^⑤
V _{GS(th)}	Gate Threshold Voltage	2.2		3.9	V	$V_{DS} = V_{GS}, I_D = 150 \mu A$
I _{DSS}	Drain-to-Source Leakage Current			1.0	uА	$V_{DS} = 40V, V_{GS} = 0V$
				150	μΑ	$V_{DS} = 40V, V_{GS} = 0V, T_{J} = 125^{\circ}C$
I _{GSS}	Gate-to-Source Forward Leakage			100	n A	V _{GS} = 20V
	Gate-to-Source Reverse Leakage			-100	nA	V _{GS} = -20V
R _G	Internal Gate Resistance		2.2		Ω	

Dynamic @ T_J = 25°C (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Units	Conditions
gfs	Forward Transconductance	122			S	$V_{DS} = 10V, I_{D} = 100A$
Q _g	Total Gate Charge		150	225		I _D = 100A
Q _{gs}	Gate-to-Source Charge		41		nC	V _{DS} =20V
Q _{gd}	Gate-to-Drain ("Miller") Charge		51	_		V _{GS} = 10V ⑤
Q _{sync}	Total Gate Charge Sync. (Q _g - Q _{gd})		99			$I_D = 100A, V_{DS} = 0V, V_{GS} = 10V$
t _{d(on)}	Turn-On Delay Time		18			$V_{DD} = 20V$
t _r	Rise Time		62		ns	I _D = 30A
t _{d(off)}	Turn-Off Delay Time		78		115	$R_{G} = 2.7\Omega$
t _f	Fall Time		51			V _{GS} = 10V ⁽⁵⁾
C _{iss}	Input Capacitance		7437			$V_{GS} = 0V$
C _{oss}	Output Capacitance		1097			V _{DS} = 25V
C _{rss}	Reverse Transfer Capacitance		748		рF	f = 1.0 MHz
C _{oss} eff. (ER)	Effective Output Capacitance (Energy Related)		1314			$V_{GS} = 0V, V_{DS} = 0V \text{ to } 32V $
C _{oss} eff. (TR)	Effective Output Capacitance (Time Related)		1735			$V_{GS} = 0V, V_{DS} = 0V \text{ to } 32V $

Diode Characteristics

Symbol	Parameter	Min.	Тур.	Max.	Units	Conditions
Is	Continuous Source Current			306 ①		MOSFET symbol
	(Body Diode)			0000	А	showing the
I _{SM}	Pulsed Source Current			1040		integral reverse
	(Body Diode) ②			1040		p-n junction diode.
V _{SD}	Diode Forward Voltage		1.0	1.3	V	$T_J = 25^{\circ}C, I_S = 100A, V_{GS} = 0V$ (5)
dv/dt	Peak Diode Recovery ④		3.5		V/ns	$T_J = 175^{\circ}C, I_S = 100A, V_{DS} = 40V$
t _{rr}	Reverse Recovery Time		37		ns -	$T_J = 25^{\circ}C$ $V_R = 34V$,
			38		115	$T_{J} = 125^{\circ}C$ $I_{F} = 100A$
Q _{rr}	Reverse Recovery Charge		34		nC	T _J = 25°C di/dt = 100A/µs ⑤
			36			$T_J = 125^{\circ}C$
I _{RRM}	Reverse Recovery Current		1.8		Α	$T_J = 25^{\circ}C$
t _{on}	Forward Turn-On Time	Intrinsi	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)			

Notes:

- ① Calculated continuous current based on maximum allowable junction temperature. Bond wire current limit is 240A. Note that current limitations arising from heating of the device leads may occur with some lead mounting arrangements. (Refer to AN-1140)
- O Repetitive rating; pulse width limited by max. junction temperature.
- ③ Limited by T_{Jmax} , starting $T_J = 25^{\circ}C$, L = 0.069mH, $R_G = 50\Omega$, $I_{AS} = 100A$, $V_{GS} = 10V$. Part not recommended for use above this value.
- $\textcircled{I}_{SD} \leq$ 100A, di/dt \leq 1288A/µs, V_{DD} \leq V_{(BR)DSS}, T_J \leq 175°C.

- (5) Pulse width \leq 400µs; duty cycle \leq 2%.
- 6 C_{oss} eff. (TR) is a fixed capacitance that gives the same charging time as C_{oss} while V_{DS} is rising from 0 to 80% V_{DSS}.
- \oslash C_{oss} eff. (ER) is a fixed capacitance that gives the same energy as C_{oss} while V_{DS} is rising from 0 to 80% V_{DSS}.
- ⑧ When mounted on 1" square PCB (FR-4 or G-10 Material). For recommended footprint and soldering techniques refer to application note #AN-994.
- (9) R_{θ} is measured at T_J approximately 90°C.
- $Omega \in \mathsf{R}_{\theta \mathsf{JC}}$ value shown is at time zero.



TOF

воттом

VGS 15V 10V 8.0V 7.0V

6.5V

6.0V

5 5V

5.0V

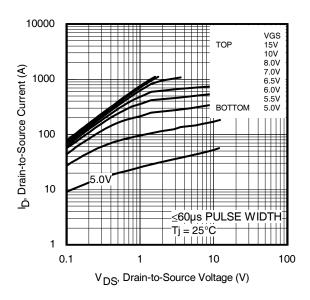
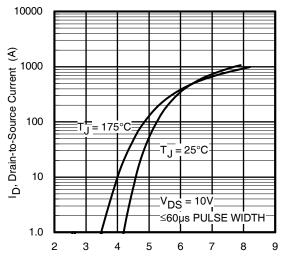


Fig 1. Typical Output Characteristics



 V_{GS} , Gate-to-Source Voltage (V) Fig 3. Typical Transfer Characteristics

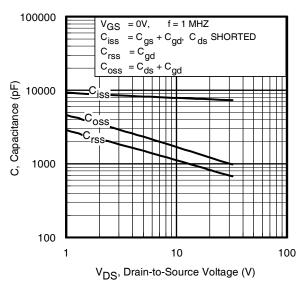
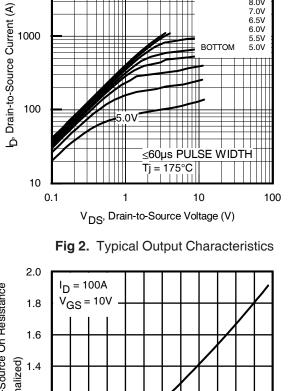
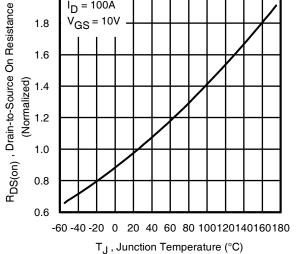


Fig 5. Typical Capacitance vs. Drain-to-Source Voltage



10000

1000





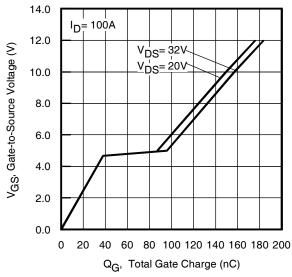
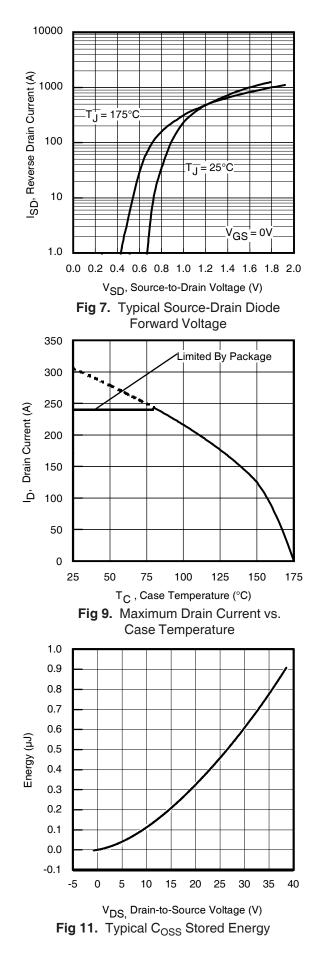


Fig 6. Typical Gate Charge vs. Gate-to-Source Voltage

3 Downloaded from Arrow.com.





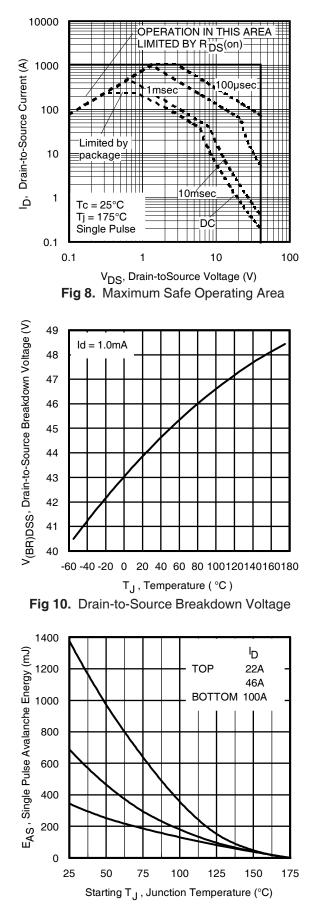


Fig 12. Maximum Avalanche Energy vs. DrainCurrent

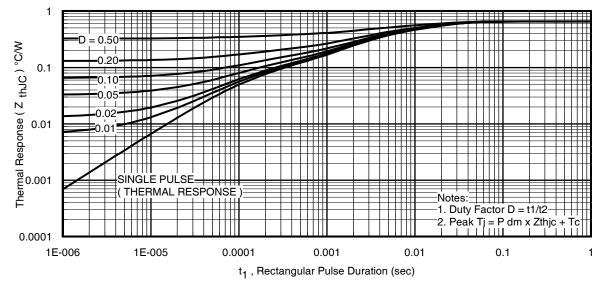


Fig 13. Maximum Effective Transient Thermal Impedance, Junction-to-Case

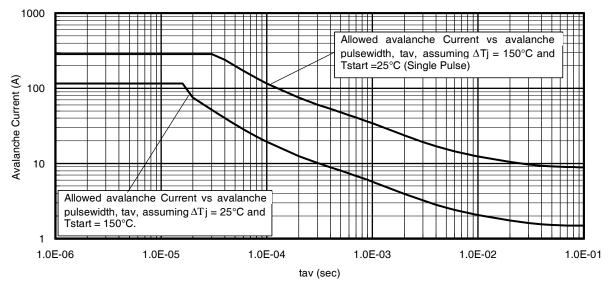
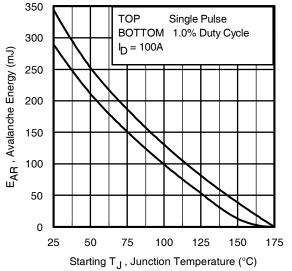


Fig 14. Typical Avalanche Current vs.Pulsewidth





Notes on Repetitive Avalanche Curves , Figures 14, 15 (For further info, see AN-1005 at www.irf.com)

- 1. Avalanche failures assumption: Purely a thermal phenomenon and failure occurs at a temperature far in
- excess of T_{jmax}. This is validated for every part type.
- 2. Safe operation in Avalanche is allowed as long asT_{jmax} is not exceeded.
- 3. Equation below based on circuit and waveforms shown in Figures 24a, 24b.
- 4. P_{D (ave)} = Average power dissipation per single avalanche pulse.
 5. BV = Rated breakdown voltage (1.3 factor accounts for voltage increase during avalanche).
- 6. I_{av} = Allowable avalanche current.
- 7. ΔT = Allowable rise in junction temperature, not to exceed T_{jmax} (assumed as 25°C in Figure 14, 15).

t_{av =} Average time in avalanche.

 $D = Duty cycle in avalanche = t_{av} \cdot f$

 $Z_{thJC}(D, t_{av})$ = Transient thermal resistance, see Figures 13)

$$\begin{split} \textbf{P}_{D \;(ave)} &= 1/2 \;(\; 1.3 \cdot \textbf{BV} \cdot \textbf{I}_{av}) = \Delta T/\; \textbf{Z}_{thJC} \\ \textbf{I}_{av} &= 2\Delta T/\; [1.3 \cdot \textbf{BV} \cdot \textbf{Z}_{th}] \\ \textbf{E}_{AS \;(AR)} &= \textbf{P}_{D \;(ave)} \cdot \textbf{t}_{av} \end{split}$$



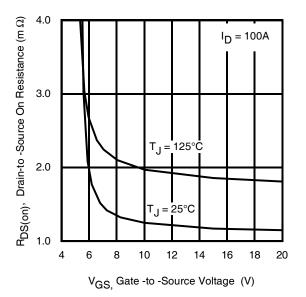


Fig 16. On-Resistance vs. Gate Voltage

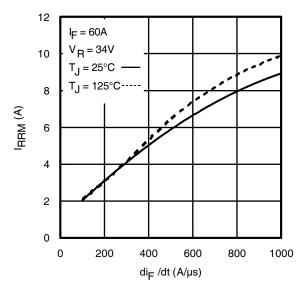
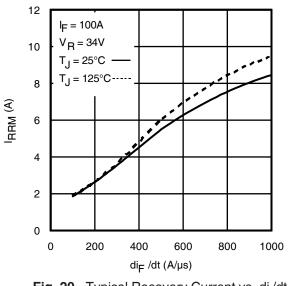
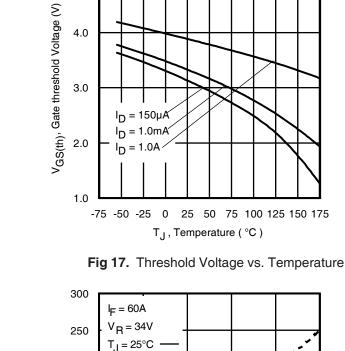


Fig. 18 - Typical Recovery Current vs. dif/dt







5.0

4.0

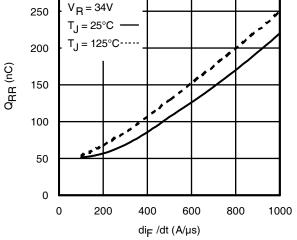
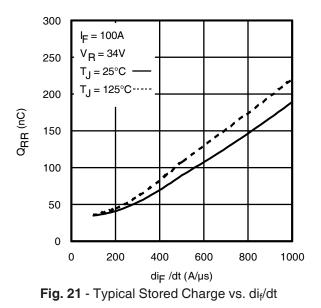


Fig. 19 - Typical Stored Charge vs. dif/dt



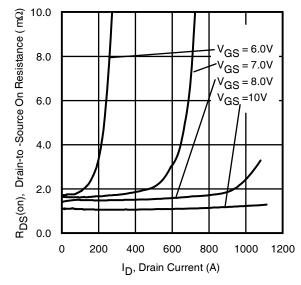
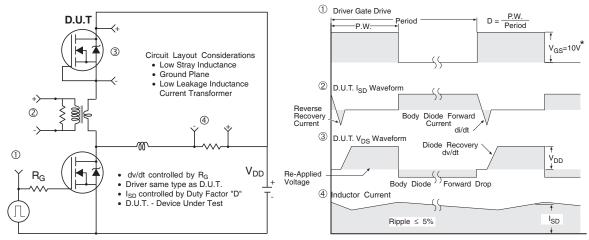


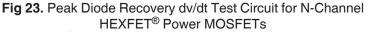
Fig 22. Typical On-Resistance vs. Drain Current



AUIRFS8407-7P



* V_{GS} = 5V for Logic Level Devices



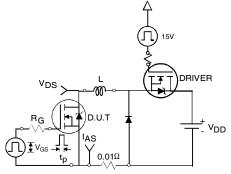


Fig 24a. Unclamped Inductive Test

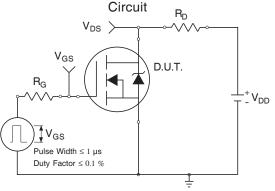


Fig 25a. Switching Time Test Circuit

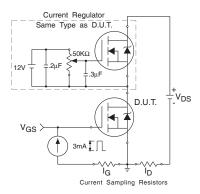


Fig 26a. Gate Charge Test Circuit

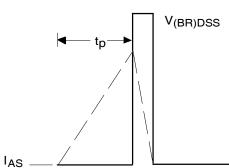


Fig 24b. Unclamped Inductive Waveforms

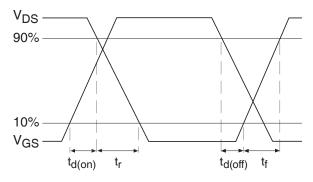


Fig 25b. Switching Time Waveforms

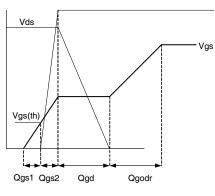


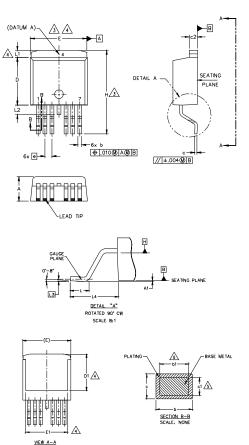
Fig 26b. Gate Charge Waveform

ld



D²Pak - 7 Pin Package Outline

Dimensions are shown in millimeters (inches)



S Y						
M B O L	MILLIMETERS		INC	N T E S		
L	Min.	MAX.	MIN.	MAX.	E S	
A	4.06	4.83	.160	.190		
A1	-	0.254	-	.010		
b	0.51	0.99	.020	.036		
ь1	0.51	0.89	.020	.032	5	
с	0.38	0.74	.015	.029		
c1	0.38	0.58	.015	.023	5	
c2	1.14	1.65	.045	.065		
D	8.38	9,65	.330	.380	3	
D1	6.86	-	.270		4	
E	9.65	10.67	.380	.420	3,4	
E1	6.22	-	.245		4	
e	1.27	BSC	.050	BSC		
н	14.61	15.88	.575	.625		
L	1,78	2.79	.070	.110		
L1	-	1.68	-	.066	4	
L2	-	1.78	-	.070		
L3	0.25	0.25 BSC		.010 BSC		
L4	4.78	5.28	.188	.208	1	

NOTES:

1. DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M-1994

2. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].

 J. DIMENSION D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED

 0.127 [.005"] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST

 EXTREMES OF THE PLASTIC BODY AT DATUM H.

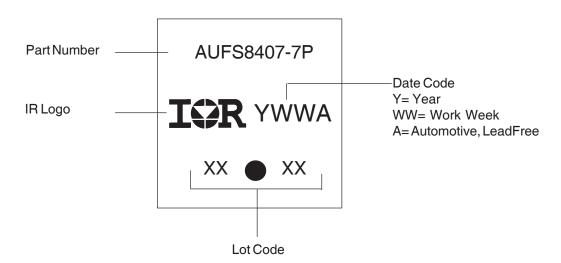
4. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSION E, L1, D1 & E1.

5. DIMENSION 61 AND c1 APPLY TO BASE METAL ONLY.

6. DATUM A & B TO BE DETERMINED AT DATUM PLANE H.

- 7. CONTROLLING DIMENSION: INCH.
- 8. OUTLINE CONFORMS TO JEDEC OUTLINE TO-263CB.

D²Pak - 7 Pin Part Marking Information

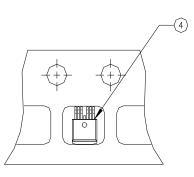


Note: For the most current drawing please refer to IR website at http://www.irf.com/package/

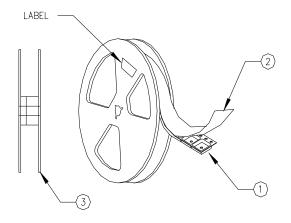
D²Pak - 7 Pin Tape and Reel

NOTES, TAPE & REEL, LABELLING:

- 1. TAPE AND REEL.
 - 1.1 REEL SIZE 13 INCH DIAMETER.
 - 1.2 EACH REEL CONTAINING 800 DEVICES.
 - 1.3 THERE SHALL BE A MINIMUM OF 42 SEALED POCKETS CONTAINED IN THE LEADER AND A MINIMUM OF 15 SEALED POCKETS IN THE TRAILER.
 - 1.4 PEEL STRENGTH MUST CONFORM TO THE SPEC. NO. 71-9667.
 - 1.5 PART ORIENTATION SHALL BE AS SHOWN BELOW.
 - 1.6 REEL MAY CONTAIN A MAXIMUM OF TWO UNIQUE LOT CODE/DATE CODE COMBINATIONS. REWORKED REELS MAY CONTAIN A MAXIMUM OF THREE UNIQUE LOT CODE/DATE CODE COMBINATIONS. HOWEVER, THE LOT CODES AND DATE CODES WITH THEIR RESPECTIVE QUANTITIES SHALL APPEAR ON THE BAR CODE LABEL FOR THE AFFECTED REEL.



- 2. LABELLING (REEL AND SHIPPING BAG).
 - 2.1 CUST. PART NUMBER (BAR CODE): IRFXXXXSTRL-7P
 - 2.2 CUST. PART NUMBER (TEXT CODE): IRFXXXXSTRL-7P
 - 2.3 I.R. PART NUMBER: IRFXXXXSTRL-7P
 - 2.4 QUANTITY:
 - 2.5 VENDOR CODE: IR
 - 2.6 LOT CODE:
 - 2.7 DATE CODE:



Qualification Information[†]

Qualification Level		Automotive (per AEC-Q101)					
		Comments: This part number(s) passed Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.					
		D ² PAK 7 Pin	MSL1				
	Machine Model	Class M3 (+/- 400V) ^{††} AEC-Q101-002					
ESD	Human Body Model	Class H2 (+/- 4000V) ^{††} AEC-Q101-001					
	Charged Device Model	Class C5 (+/- 2000V) ^{††} AEC-Q101-005					
RoHS Compliant		Yes					

† Qualification standards can be found at International Rectifier's web site: http://www.irf.com/

†† Highest passing voltage.



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